

Vishay Siliconix

# N-Channel 25 V (D-S) MOSFET

### **DESCRIPTION**

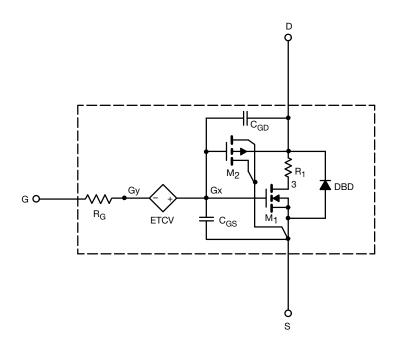
The attached SPICE model describes the typical electrical characteristics of the n-channel vertical DMOS. The subcircuit model is extracted and optimized over the -  $55\,^{\circ}$ C to +  $125\,^{\circ}$ C temperature ranges under the pulsed 0 V to 10 V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched  $C_{gd}$  model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

### **CHARACTERISTICS**

- N-Channel Vertical DMOS
- Macro Model (Subcircuit Model)
- Level 3 MOS
- Apply for both Linear and Switching Application
- Accurate over the 55 °C to + 125 °C Temperature Range
- Model the Gate Charge

#### SUBCIRCUIT MODEL SCHEMATIC



#### Note

This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.



# **SPICE Device Model SiE878DF**

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SPECIFICATIONS T <sub>J</sub> = 25 °C, unless otherwise noted					
PARAMETER	SYMBOL	TEST CONDITIONS	SIMULATED DATA	MEASURED DATA	UNIT
Static					
Gate-Source Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_D = 250 \mu A$	1.5	-	٧
Drain-Source On-State Resistance <sup>a</sup>	R <sub>DS(on)</sub>	$V_{GS} = 10 \text{ V}, I_D = 20 \text{ A}$	0.0043	0.0042	Ω
		$V_{GS} = 4.5 \text{ V}, I_D = 20 \text{ A}$	0.0056	0.0055	
Forward Transconductance <sup>a</sup>	g <sub>fs</sub>	$V_{DS} = 15 \text{ V}, I_D = 20 \text{ A}$	77	74	S
Body Diode Voltage	$V_{SD}$	I <sub>S</sub> = 10 A	0.8	0.8	V
Dynamic <sup>b</sup>					
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> = 12.5 V, V <sub>GS</sub> = 0 V, f = 1 MHz	1370	1400	pF
Output Capacitance	C <sub>oss</sub>		398	400	
Reverse Transfer Capacitance	C <sub>rss</sub>		143	145	
Total Gate Charge	$Q_g$	$V_{DS} = 12.5 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 20 \text{ A}$	22	24	nC
		V <sub>DS</sub> = 12.5 V, V <sub>GS</sub> = 4.5 V, I <sub>D</sub> = 20 A	11	11.2	
Gate-Source Charge	$Q_{gs}$		4.2	4.2	
Gate-Drain Charge	Q <sub>gd</sub>		3	3	

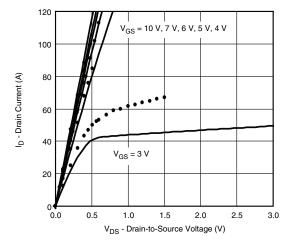
#### **Notes**

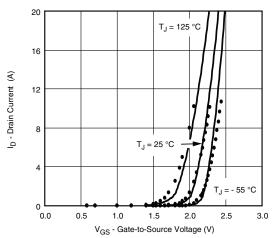
- a. Pulse test; pulse width  $\leq 300~\mu s,~duty~cycle \leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.

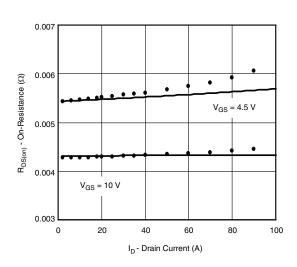
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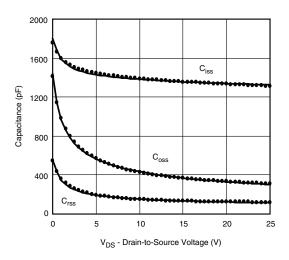
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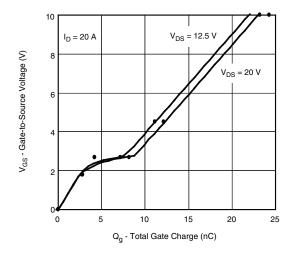
## COMPARISON OF MODEL WITH MEASURED DATA $T_J = 25~{}^{\circ}\text{C}$ , unless otherwise noted

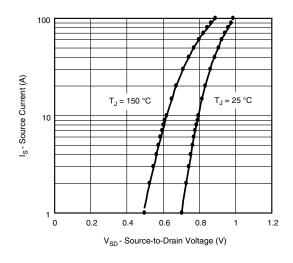










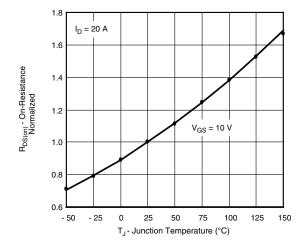


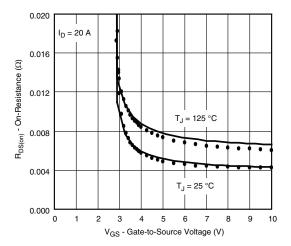
**Note**Dots and squares represent measured data.

# **SPICE Device Model SiE878DF**

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## COMPARISON OF MODEL WITH MEASURED DATA $T_J = 25~^{\circ}\text{C}$ , unless otherwise noted





#### Note

Dots and squares represent measured data.



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